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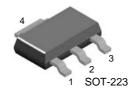
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January 2007



## **NZT605 NPN Darlington Transistor**

- This device designed for applications requiring extremely high gain at collector currents to 1.0A and high breakdown voltage.
- Sourced from process 06.



1. Base 2.4. Collector 3. Emitter

## Absolute Maximum Ratings \* T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	110	V
V <sub>CBO</sub>	Collector-Base Voltage	140	V
V <sub>EBO</sub>	Emitter-Base Voltage	10	V
I <sub>C</sub>	Collector Current - Continuous	1.5	A
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

These ratings are based on a maximum junction temperature of 150 degrees C.
These are steady limits. The factory should be consulted on application involving pulsed or low duty cycle operations

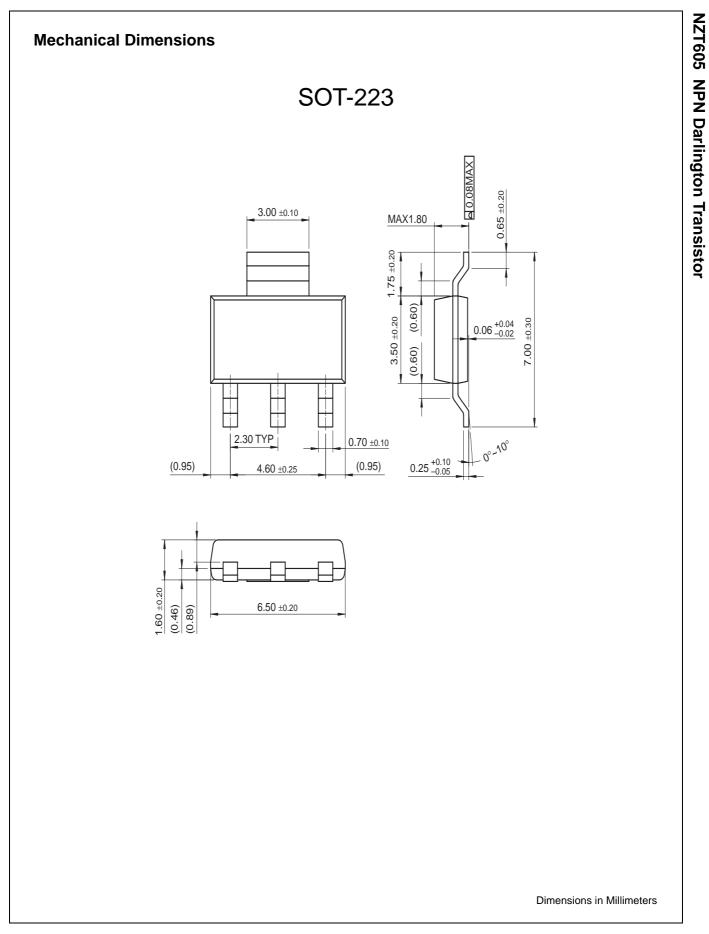
#### Electrical Characteristics \* T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Max	Units
Off Characte	ristics				
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage *	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$	110		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \mu A, I_{\rm E} = 0$	140		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_{E} = 100 \mu A, I_{C} = 0$	10		V
I <sub>CBO</sub>	Collector Cutoff Current	$V_{CB} = 120V, I_E = 0$		10	nA
I <sub>CES</sub>	Collector Cutoff Current	$V_{CE} = 120V, I_E = 0$		10	nA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 8.0V, I_{C} = 0$		100	nA
On Characte	ristics *	·			
h <sub>FE</sub>	DC Current Gain	$V_{CE} = 5.0V, I_C = 50MA$ $V_{CE} = 5.0V, I_C = 500MA$ $V_{CE} = 5.0V, I_C = 1.0A$ $V_{CE} = 5.0V, I_C = 1.5A$ $V_{CE} = 5.0V, I_C = 2.0A$	2000 5000 2000 300 200	100K	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$I_{C} = 250$ mA, $I_{B} = 0.25$ mA $I_{C} = 1.0$ A, $I_{B} = 1.0$ mA		1 1.5	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 1.0A, I <sub>B</sub> = 1.0mA		1.8	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 1.0A, V <sub>CE</sub> = 5.0V		1.7	V
Small Signal	characteristics				
f <sub>T</sub>	Transition Frequency	I <sub>C</sub> = 100mA, V <sub>CE</sub> = 10V, f = 20MHz	150		MHz

## Thermal Characteristics $T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Max.	Units	
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	1,000 8.0	m₩ mW/°C	
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	125	°C/W	

\* Device mounted on FR-4PCB 36mm  $\times$  18mm  $\times$  1.5mm; mounting pad for the collector lead min. 6cm²





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